

1N5817M / 1N5818M / 1N5819M

1.0A SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Features

- High Current Capability
- Low Forward Voltage Drop
- Guard Ring for Transient Protection
- Glass Package for High Reliability
- Packaged for Surface Mount Applications

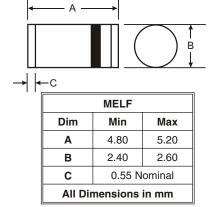
Mechanical Data

Case: MELF, Glass

• Terminals: Solderable per MIL-STD-202,

Method 208

Polarity: Cathode band
Approx Weight: 0.25 gram
Mounting Position: Any



Maximum Ratings and Electrical Characteristics @ TA = 25°C unless otherwise specified

Characteristic	Symbol	1N5817M	1N5818M	1N5819M	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	20	30	40	V
RMS Reverse Voltage	V _{R(RMS)}	14	21	28	V
Maximum Average Forward Rectified Current @T _T = 90°C (Note 1)	Io	1.0			А
Maximum Forward Surge Current. Half Cycle @60Hz Superimposed on rated load, JEDEC Method	I _{FSM}	25			А
	V _F	0.450 0.750	0.550 0.875	0.600 0.900	V
Maximum Reverse Leakage Current @ V_{RRM} @ $T_A = 25^{\circ}C$ @ $T_A = 100^{\circ}C$	I _R	1.0 10			mA
Typical Thermal Resistance, Junction to Ambient (Note 1)	$R_{\theta JA}$	130			K/W
Typical Junction Capacitance (Note 2)	C _j	110			pF
Storage and Operating Temperature Range	T _j , T _{STG}	-60 to +125			°C

Notes: 1. Valid provided that terminals are kept at ambient temperature.

2. Measured at $V_R = 4.0V$, f = 1.0MHz.

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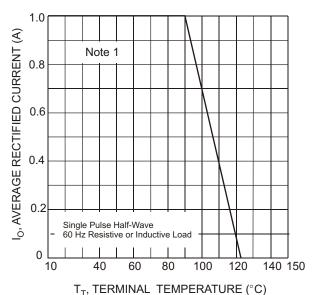
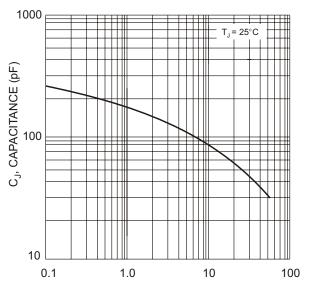
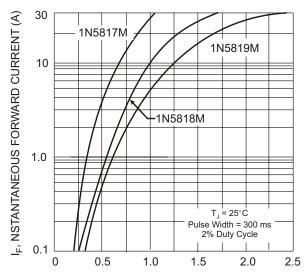


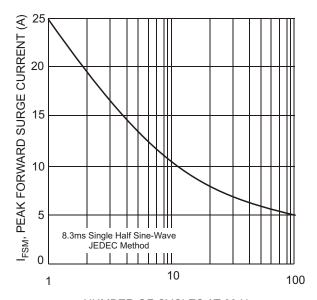
Fig. 1, Forward Current Derating Curve



V_R, REVERSE VOLTAGE (V) Fig. 3, Typical Junction Capacitance



V_F, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2, Typical Forward Characteristics



NUMBER OF CYCLES AT 60 Hz Fig. 4, Maximum Non-Repetitive Peak Fwd Surge Current